

Docket No.: 2336-257

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	
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Seung Wan CHAE <i>et al.</i>	:	Confirmation No. 2845
	:	
U.S. Patent Application No. 10/811,808	:	Group Art Unit: 2814
	:	
Filed: March 30, 2004	:	Examiner: Wai Sing Louie
For:		
GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE AND METHOD FOR MANUFACTURING THE SAME		

**AMENDMENT/SUBMISSION UNDER RULE 114**

COMMISSIONER FOR PATENTS  
P.O. Box 1450  
Alexandria VA 22313-1450

Sir:

In response to the final Office Action mailed March 8, 2006, and in conjunction with the accompanying Request for Continued Examination, the following amendments and remarks are respectfully submitted in connection with the above-identified application.